

# Dual Line ESD Protection Diode Array UM5082 DFN3 1.0×0.6

#### **General Description**

The UM5082 ESD protection diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. It features large cross-sectional area junctions for conducting high transient currents, offers desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs.

The UM5082 ESD protection diode protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The UM5082 is available in a SLP1006P3 package with working voltages of 5 volt.

It gives designer the flexibility to protect one or two unidirectional line in applications where arrays are not practical. Additionally, it may be "sprinkled" around the board in applications where board space is at a premium. It may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 ( $\pm 15 \text{kV}$  air,  $\pm 8 \text{kV}$  contact discharge).

#### **Applications**

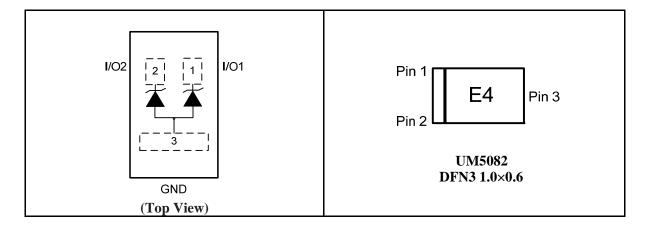
- Cell Phone Handsets and Accessories
- Microprocessor Based Equipments
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentations
- Cordless Phones
- Digital Cameras
- Peripherals
- MP3 Players

#### **Features**

- Transient Protection for Data & Power Lines to IEC 61000-4-2 (ESD) ±15kV(Air), IEC 61000-4-2 (ESD) ±8kV (Contact)
- Small Package for Use in Portable Electronics
- Suitable Replacement for MLV's in ESD Protection Applications
- Protect One or Two I/O Lines
- Low Clamping Voltage
- Stand-Off Voltage: 5V
- Low Leakage Current
- Solid-State Silicon-Avalanche Technology

#### **Pin Configurations**

#### **Top View**





# **Ordering Information**

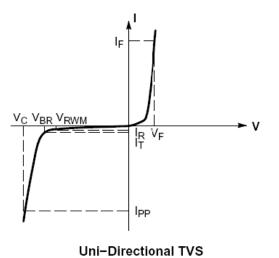
Part Number	Working Voltage	Packaging Type	Channel	Marking Code	Shipping Qty
UM5082	5.0V	DFN3 1.0×0.6	2	E4	10000pcs/7 Inch Tape & Reel

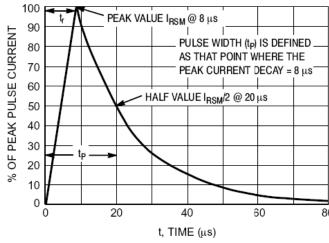
## **Absolute Maximum Ratings**

Rating	Symbol	Value	Unit
Peak Pulse Power (t <sub>P</sub> =8/20μs)	$P_{PK}$	140	Watts
Maximum Peak Pulse Current (t <sub>P</sub> =8/20μs)	$I_{PP}$	11	Amps
Lead Soldering Temperature	$T_{ m L}$	260 (10 sec.)	°C
Operating Temperature	$T_J$	-55 to +125	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

# **Symbol Definition**

Parameter	Symbol
Maximum Reverse Peak Pulse Current	$I_{PP}$
Clamping Voltage @ I <sub>pp</sub>	$V_{\rm C}$
Working Peak Reverse Voltage	$V_{ m RWM}$
Maximum Reverse Leakage Current @ V <sub>RWM</sub>	$I_R$
Breakdown Voltage @ I <sub>T</sub>	$V_{BR}$
Test Current	$I_{T}$
Forward Current	$I_{\mathrm{F}}$
Forward Voltage @ I <sub>F</sub>	$V_{\mathrm{F}}$
Peak Power Dissipation	$P_{PK}$
Max. Capacitance @ V <sub>R</sub> =0V, f=1MHz	С







#### **Electrical Characteristics**

(T=25°C, Device for 5.0V Reverse Stand-Off Voltage)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Reverse Stand-Off Voltage	$V_{RWM}$				5	V	
Reverse Breakdown Voltage	$V_{\text{BR}}$	I <sub>T</sub> =1mA	6	6.8	7.2	V	
Reverse Leakage Current	$I_R$	$V_{RWM}=5V$ , $T=25$ °C			1	μΑ	
Clausia - Valtara	<b>V</b> 7	$I_{PP}=5A, t_{P}=8/20 \mu s$			9.7	V	
Clamping Voltage	$ m V_{C}$	$I_{PP}=11A, t_{P}=8/20 \mu s$			13.6	V	
Forward Voltage	$V_{\mathrm{F}}$	I <sub>F</sub> =10mA		0.8		V	
Junction Capacitance	$C_{J}$	$V_R=0V$ , $f=1MHz$		40	55	pF	
Junction Capacitance	$C_{J}$	$V_R$ =2.5V, f=1MHz		30	40	pF	

#### **Applications Information**

#### **Device Connection Options**

UM5082 ESD protection diode is designed to protect one or two I/O lines. The device is unidirectional and may be used on lines where the signal polarity is above ground. The cathode band should be placed towards the line that is to be protected.

#### Circuit Board Layout Recommendations for Suppression of ESD

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

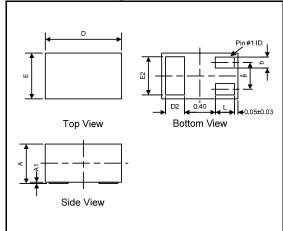
- 1. Place the TVS near the input terminals or connectors to restrict transient coupling.
- 2. Minimize the path length between the TVS and the protected line.
- 3. Minimize all conductive loops including power and ground loops.
- 4. The ESD transient return path to ground should be kept as short as possible.
- 5. Never run critical signals near board edges.
- 6. Use ground planes whenever possible. For multilayer printed-circuit boards, use ground vias.
- 7. Keep parallel signal paths to a minimum.
- 8. Avoid running protection conductors in parallel with unprotected conductor.
- 9. Minimize all printed-circuit board conductive loops including power and ground loops.
- 10. Avoid using shared transient return paths to a common ground point.



# **Package Information**

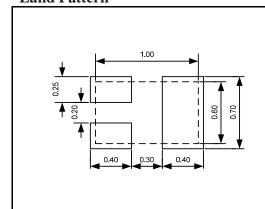
# UM5082 DFN3 1.0×0.6

# **Outline Drawing**



DIMENSIONS							
C	MILLIMETERS			INCHES			
Symbol	Min	Тур	Max	Min	Тур	Max	
A	0.45	0.50	0.55	0.018	0.020	0.022	
A1	0.00	0.03	0.05	0.000	0.001	0.002	
b	0.10	0.15	0.20	0.004	0.006	0.008	
D	0.95	1.00	1.075	0.037	0.039	0.042	
D2	0.20	0.25	0.30	0.008	0.010	0.012	
Е	0.55	0.60	0.675	0.022	0.024	0.027	
E2	0.45	0.50	0.55	0.018	0.020	0.022	
e	0.35TYP			0.014TYP			
L	0.20	0.25	0.30	0.008	0.010	0.012	

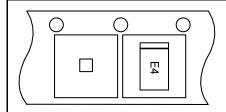
## **Land Pattern**



#### NOTES:

- 1. Compound dimension: 1.00×0.60;
- 2. Unit: mm;
- 3. General tolerance  $\pm 0.05$ mm unless otherwise specified;
- 4. The layout is just for reference.

# **Tape and Reel Orientation**





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